



NTE56039 TRIAC, 4A Sensitive Gate

Description:

The NTE56039 is a glass passivated TRIAC in a plastic SOT82 type package designed for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants.

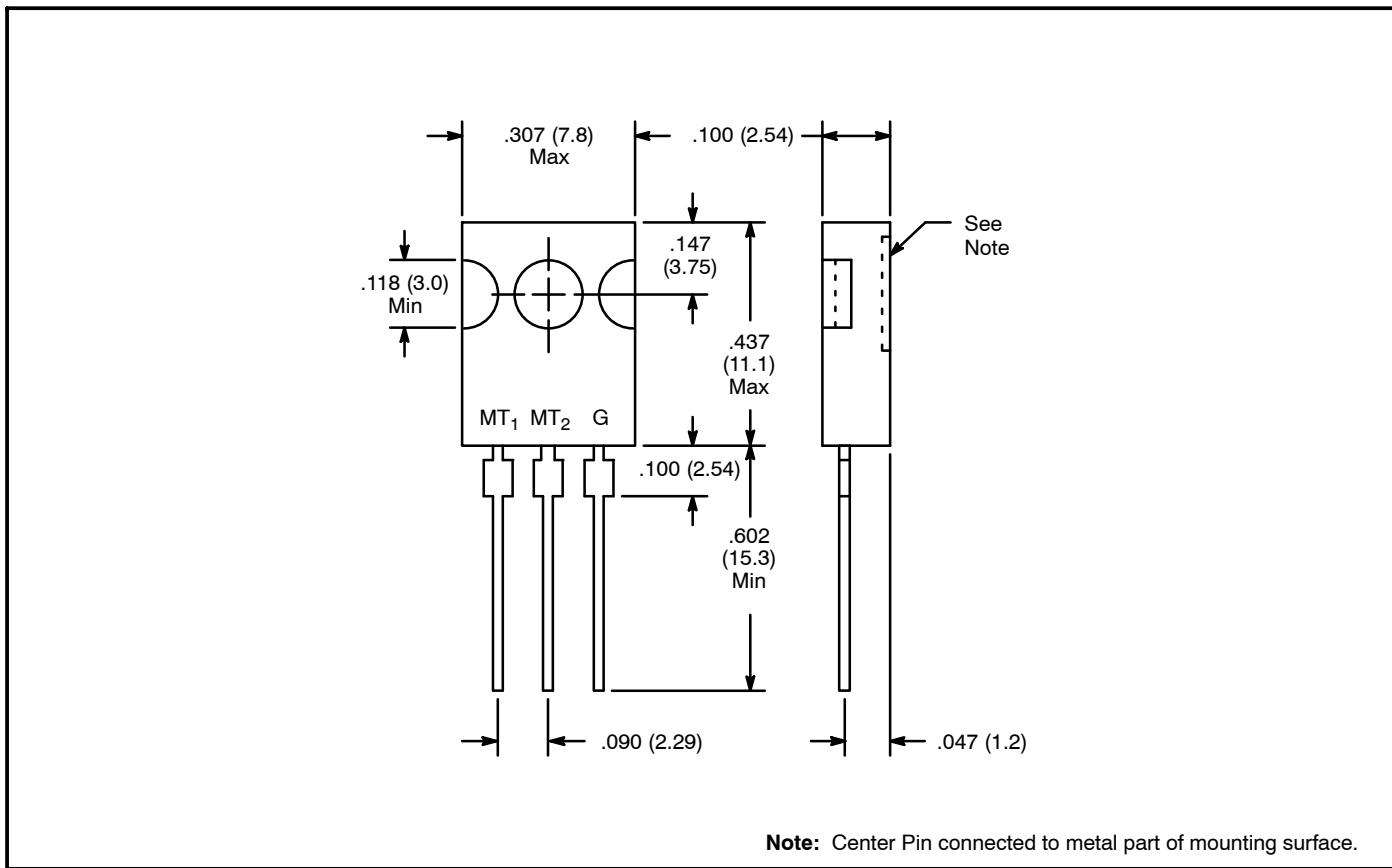
Absolute Maximum Ratings:

Repetitive Peak Off-State Voltage (Note 1), V_{DRM}	600V
RMS On-State Current (Full Sine Wave, $T_{MB} \leq 107^\circ\text{C}$), $I_T(\text{RMS})$	4A
Non-Repetitive Peak On-State Current (Full Sine Wave, $T_J = +25^\circ\text{C}$ prior to Surge), I_{TSM}	
$t = 20\text{ms}$	25A
$t = 16.7\text{ms}$	27A
I^2t for Fusing ($t = 10\text{ms}$), I^2t	3.1A ² sec
Repetitive Rate-of-Rise of On-State Current after Triggering, dI_T/dt	
($I_{TM} = 6\text{A}$, $I_G = 0.2\text{A}$, $dI_G/dt = 0.2\text{A}/\mu\text{s}$)	
MT ₂ (+), G (+)	50A/ μs
MT ₂ (+), G (-)	50A/ μs
MT ₂ (-), G (-)	50A/ μs
MT ₂ (-), G (+)	10A/ μs
Peak Gate Current, I_{GM}	2A
Peak Gate Voltage, V_{GM}	5V
Peak Gate Power, P_{GM}	5W
Average Gate Power (Over Any 20ms Period), $P_{G(AV)}$	500mW
Operating Junction Temperature, T_J	+125°C
Storage Temperature Range, T_{stg}	-40° to +150°C
Thermal Resistance, Junction-to-Mounting Base, R_{thJMB}	
Full Cycle	3.0K/W
Half Cycle	3.7K/W
Typical Thermal Resistance, Junction-to-Ambient, R_{thJA}	100K/W

Note 1. Although not recommended, off-state voltages up to 800V may be applied without damage, but the TRIAC may switch to the On-State. The rate-of-rise of current should not exceed 3A/ μs .

Electrical Characteristics: ($T_J = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Gate Trigger Current MT ₂ (+), G (+)	I _{GT}	V _D = 12V, I _T = 0.1A	-	2.5	10	mA
			-	4.0	10	mA
			-	5.0	10	mA
			-	11.0	25	mA
Latching Current MT ₂ (+), G (-)	I _L	V _D = 12V, I _T = 0.1A	-	3.0	15	mA
			-	10	20	mA
			-	2.5	15	mA
			-	4.0	20	mA
Holding Current	I _H	V _D = 12V, I _T = 0.1A	-	2.2	15	mA
On-State Voltage	V _T	I _T = 5A	-	1.4	1.7	V
Gate Trigger Voltage	V _{GT}	V _D = 12V, I _T = 0.1A	-	0.7	1.5	V
		V _D = 400V, I _T = 0.1A, T _J = +125°C	0.25	0.4	-	V
Off-State Leakage Current	I _D	V _D = 600V, T _J = +125°C	-	0.1	0.5	mA
Dynamic Characteristics						
Critical Rate-of-Rise of Off-State Voltage	dV _D /dt	V _{DM} = 402V, T _J = +125°C, Exponential Waveform, Gate Open	-	50	-	V/μs
Gate Controlled Turn-On Time	t _{gt}	I _{TM} = 6A, V _D = 600V, I _G = 0.1A, dI _G /dt = 5A/μs	-	2	-	μs



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